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## NTE2080 Integrated Circuit 7-Stage Driver Array

### **Features:**

- Low Output Saturation Voltage
- Protective Diodes Guard Against Negative Inputs
- Spark Killer Diodes Accommodate L-Loads
- Equipped with a Strobe Terminal to Cut Off Outputs
- With 7 Units, it is Ideal for 14-Digit Printers

### **Applications:**

- Driving Battery-Operated Compact Printers
- Driving Various Relays
- Driving LED Lamps and Other Display Elements
- Interfacing with MOS or Bipolar Logic IC

### **Absolute Maximum Ratings:** ( $T_A = +25^\circ\text{C}$ unless otherwise specified)

Output Supply Voltage, $V_{\text{OUT}}$ .....	-0.3V to +11V
Input Supply Voltage, $V_{\text{IN(1)}}$ .....	-35V to +20V
Strobe Supply Voltage, $V_{\text{IN(2)}}$ .....	0V to +10V
Maximum Power Supply Voltage, $V_{\text{CCmax}}$ .....	-0.3V to +9V
Output Inflow Current (Per Unit, at $V_{\text{IH}}$ ), $I_{\text{OUT}}$ .....	100mA
Instantaneous Output Inflow Current (Per Unit, Note 1), $I_{\text{op}}$ .....	150mA
Spark-Killer Diode Forward Current (Per Unit, Note 1), $I_{F(s)}$ .....	150mA
GND-Pin Outflow Current (Note 1), $I_g$ .....	-1050mA
$V_{\text{CC}}$ Instantaneous Outflow Current (Note 1), $I_{\text{ccp}}$ .....	-1050mA
Allowable Power Dissipation ( $T_A = +55^\circ\text{C}$ ), $P_{\text{Dmax}}$ .....	500mW
Operating Ambient Temperature Range, $T_{\text{opg}}$ .....	-20° to +80°C
Storage Ambient Temperature Range, $T_{\text{stg}}$ .....	-40° to +125°C

Note 1. Pulse Width < 35ms at  $V_{\text{IH}}$ , Duty Cycle = 10%.

### **Allowable Operating Conditions:** ( $T_A = +25^\circ\text{C}$ unless otherwise specified)

Supply Voltage, $V_{\text{CC}}$ .....	3.5V to 9V
Input H-Level Voltage ( $I_{\text{OUT}} = 100\text{mA}$ ), $V_{\text{IH}}$ .....	8V to 20V
Input L-Level Voltage ( $I_{\text{OUT}} = 100\mu\text{A}$ ), $V_{\text{IL}}$ .....	-30V to +1V
ST Input H-Level ( $V_{\text{IN}} = 20\text{V}$ , $I_{\text{OUT}} = 100\mu\text{A}$ ), $V_{\text{SH}}$ .....	2V to 8V
ST Input L-Level ( $V_{\text{IN}} = 20\text{V}$ , $I_{\text{OUT}} = 100\mu\text{A}$ ), $V_{\text{SL}}$ .....	0V to 0.3V
Load Inductance ("L" With Spark-Killer Diodes Employed), $L_L$ .....	$\leq 100\text{mH}$

**Electrical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Output Voltage	$V_{\text{OUT}}$	$V_{\text{IN}} = 8\text{V}, V_{\text{CC}} = 6\text{V}, I_{\text{OUT}} = 100\text{mA}$	—	—	0.25	V
		$I_{\text{IN}} = 300\mu\text{A}, V_{\text{CC}} = 6\text{V}, I_{\text{OUT}} = 100\text{mA}$	—	—	0.25	V
		$I_{\text{IN}} = 300\mu\text{A}, V_{\text{CC}} = 8\text{V}, I_{\text{OUT}} = 150\text{mA}$	—	—	0.5	V
Output Sustaining Voltage	$V_{\text{O(sus)}}$	$V_{\text{IN}} = \text{Open}, t < 10\mu\text{s}, I_{\text{OUT}} = 150\text{mA}$	11	—	—	V
Output Leakage Current	$I_{\text{off}}$	$V_{\text{IN}} = 1\text{V}, V_{\text{CC}} = 9\text{V}$	—	—	100	$\mu\text{A}$
Input Current	$I_{\text{In}}$	$V_{\text{IN}} = 20\text{V}, I_{\text{OUT}} = 0$	—	—	1.8	mA
Input Leakage Current	$I_{\text{Leak}}$	$V_{\text{IN}} = -30\text{V}$	-10	—	—	$\mu\text{A}$
Spark-Killer Diode Leakage Current	$I_{\text{leak(s)}}$	$V_{\text{OUT}} = 0, V_{\text{CC}} = 8\text{V}$	—	—	30	$\mu\text{A}$
Spark-Killer Diode Forward Voltage	$V_{\text{F(s)}}$	$I_{\text{F(s)}} = 150\text{mA}$	—	—	1.7	V
Power Supply Current Strobe HI	$I_{\text{IDL}}$	$V_{\text{IN}} = 20\text{V}, V_{\text{CC}} = 9\text{V}$	—	—	18	mA

Pin Connection Diagram

